Preferred Devices

Surface Mount Ultrafast Power Rectifiers

This series employs the state-of-the-art epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for high voltage, high frequency rectification, or as free wheeling and protection diodes, in surface mount applications where compact size and weight are critical to the system.

Features

- Small Compact Surface Mountable Package with J-Bend Leads
- Rectangular Package for Automated Handling
- Highly Stable Oxide Passivated Junction
- Low Forward Voltage Drop (0.71 to 1.05 Volts Max @ 3.0 A, T_J = 150°C)
- Pb-Free Packages are Available

Mechanical Characteristics

- Case: Epoxy, Molded
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight: 217 mg (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped in 16 mm Tape and Reel, 2500 units per reel
- Polarity: Notch in Plastic Body Indicates Cathode Lead
- Device Meets MSL1 Requirements
- ESD Ratings: Machine Model, C (> 400 V) Human Body Model, 3B (> 8000 V)



ON Semiconductor®

http://onsemi.com

ULTRAFAST RECTIFIERS 3.0 AMPERES 200-600 VOLTS



SMC CASE 403 PLASTIC

MARKING DIAGRAM



U3 = Specific Device Code

x = D, G, or J

A = Assembly Location

Y = Year

WW= Work Week

ORDERING INFORMATION

| Device | Package | Shipping [†] | |
|------------|------------------|-----------------------|--|
| MURS320T3 | SMC | 2500/Tape & Reel | |
| MURS320T3G | SMC (Pb-Free) | 2500/Tape & Reel | |
| MURS340T3 | SMC | 2500/Tape & Reel | |
| MURS340T3G | SMC (Pb-Free) | 2500/Tape & Reel | |
| MURS360T3 | SMC | 2500/Tape & Reel | |
| MURS360T3G | SMC (Pb-Free) | 2500/Tape & Reel | |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

MAXIMUM RATINGS

| Rating | Symbol | MURS320T3 | MURS340T3 | MURS360T3 | Unit |
|--|--|--|--|--|------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _R | 200 | 400 | 600 | V |
| Average Rectified Forward Current | I _{F(AV)} | 3.0 @ T _L = 140°C 4.0 @ T _L = 130°C | 3.0 @ T _L = 130°C 4.0 @ T _L = 115°C | 3.0 @ T _L = 130°C 4.0 @ T _L = 115°C | Α |
| Non-Repetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz) | I _{FSM} | 75 | | A | |
| Operating Junction Temperature | TJ | - 65 to +175 | | °C | |

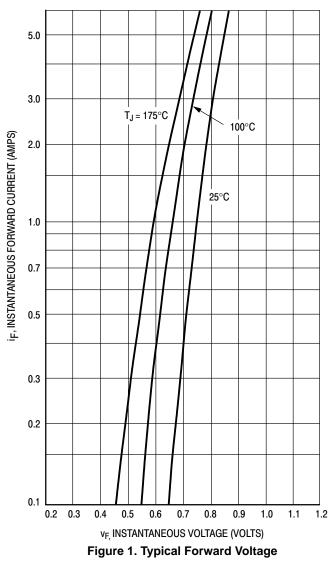
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

| Thermal Resistance, Junction-to-Lead | $R_{	heta JL}$ | . 11 | | | °C/W |
|---|-----------------|-----------------------|----------------------|----------------------|------|
| ELECTRICAL CHARACTERISTICS | | | | | |
| Maximum Instantaneous Forward Voltage (Note 1) $ \begin{aligned} &(i_F=3.0\text{ A}, T_J=25^\circ\text{C})\\ &(i_F=4.0\text{ A}, T_J=25^\circ\text{C})\\ &(i_F=3.0\text{ A}, T_J=150^\circ\text{C}) \end{aligned} $ | V _F | 0.875 0.89 0.71 | 1.25 1.28 1.05 | 1.25 1.28 1.05 | V |
| Maximum Instantaneous Reverse Current (Note 1) (Rated dc Voltage, $T_J = 25$ °C) (Rated dc Voltage, $T_J = 150$ °C) | i _R | 5.0 150 | 10 250 | 10 250 | μΑ |
| Maximum Reverse Recovery Time ($i_F = 1.0 \text{ A}, \text{ di/dt} = 50 \text{ A/}\mu\text{s}$) ($i_F = 0.5 \text{ A}, i_R = 1.0 \text{ A}, I_{REC} \text{ to } 0.25 \text{ A}$) | t _{rr} | 35 25 | 75 50 | 75 50 | ns |
| Maximum Forward Recovery Time (i _F = 1.0 A, di/dt = 100 A/μs, Recovery to 1.0 V) | t _{fr} | 25 | 50 | 50 | ns |

^{1.} Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

MURS320T3



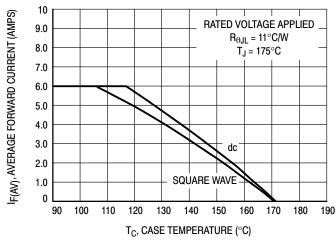


Figure 4. Current Derating, Case

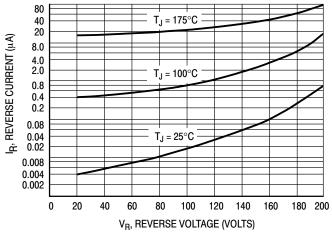


Figure 2. Typical Reverse Current*

* The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these same curves if V_R is sufficiently below rated V_R .

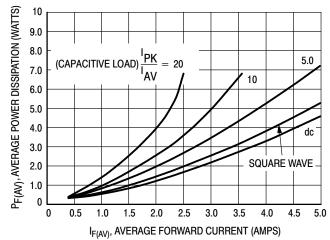


Figure 3. Power Dissipation

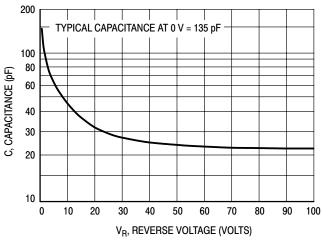


Figure 5. Typical Capacitance

MURS340T3, MURS360T3

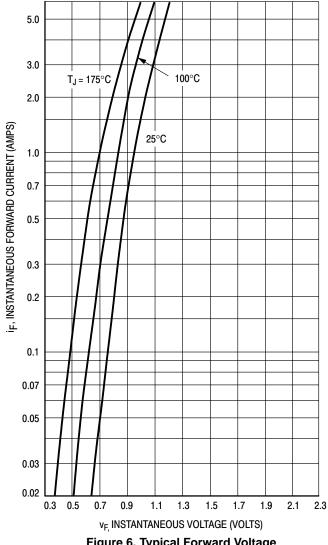


Figure 6. Typical Forward Voltage

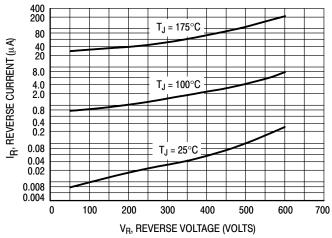


Figure 7. Typical Reverse Current*

* The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these same curves if V_R is sufficiently below rated V_R.

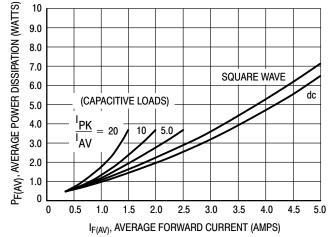


Figure 8. Power Dissipation

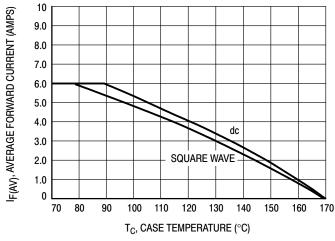


Figure 9. Current Derating, Case

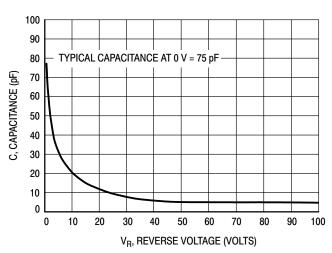
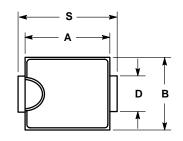
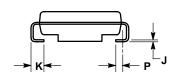


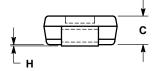
Figure 10. Typical Capacitance

PACKAGE DIMENSIONS

SMC PLASTIC PACKAGE CASE 403-03 ISSUE D



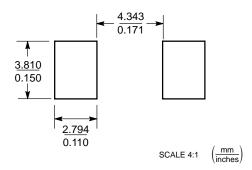




- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. D DIMENSION SHALL BE MEASURED WITHIN DIMENSION P.
 4. 403-01 THRU -02 OBSOLETE, NEW STANDARD 403-03.

| | INCHES | | MILLIMETERS | | |
|-----|-----------|--------|-------------|-------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | 0.260 | 0.280 | 6.60 | 7.11 | |
| В | 0.220 | 0.240 | 5.59 | 6.10 | |
| C | 0.075 | 0.095 | 1.90 | 2.41 | |
| D | 0.115 | 0.121 | 2.92 | 3.07 | |
| Н | 0.0020 | 0.0060 | 0.051 | 0.152 | |
| J | 0.006 | 0.012 | 0.15 | 0.30 | |
| K | 0.030 | 0.050 | 0.76 | 1.27 | |
| P | 0.020 REF | | 0.51 REF | | |
| S | 0.305 | 0.320 | 7.75 | 8.13 | |

SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 61312, Phoenix, Arizona 85082–1312 USA Phone: 480–829–7710 or 800–344–3860 Toll Free USA/Canada Fax: 480–829–7709 or 800–344–3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800–282–9855 Toll Free LISA/Canada

Japan: ON Semiconductor, Japan Customer Focus Center 2–9–1 Kamimeguro, Meguro–ku, Tokyo, Japan 153–0051 Phone: 81–3–5773–3850

ON Semiconductor Website: http://onsemi.com

Order Literature: http://www.onsemi.com/litorder

For additional information, please contact your local Sales Representative.